

Features

- Zero input-output propagation delay, adjustable by capacitive load on FBK input
- Multiple configurations, see "Available CY2308 Configurations" table
- · Multiple low-skew outputs
 - Output-output skew less than 200 ps
 - Device-device skew less than 700 ps
 - Two banks of four outputs, three-stateable by two select inputs
- 10-MHz to 133-MHz operating range
- Low jitter, less than 200 ps cycle-cycle (-1, -1H, -4, -5H)
- Space-saving 16-pin 150-mil SOIC package or 16-pin TSSOP
- 3.3V operation
- Industrial Temperature available

Functional Description

The CY2308 is a 3.3V Zero Delay Buffer designed to distribute high-speed clocks in PC, workstation, datacom, telecom, and other high-performance applications.

The part has an on-chip PLL which locks to an input clock presented on the REF pin. The PLL feedback is required to be driven into the FBK pin, and can be obtained from one of the outputs. The input-to-output skew is guaranteed to be less than 350 ps, and output-to-output skew is guaranteed to be less than 200 ps.

3.3V Zero Delay Buffer

The CY2308 has two banks of four outputs each, which can be controlled by the Select inputs as shown in the table "Select Input Decoding." If all output clocks are not required, Bank B can be three-stated. The select inputs also allow the input clock to be directly applied to the output for chip and system testing purposes.

The CY2308 PLL enters a power-down state when there are no rising edges on the REF input. In this mode, all outputs are three-stated and the PLL is turned off, resulting in less than 50 μ A of current draw. The PLL shuts down in two additional cases as shown in the "Select Input Decoding" table.

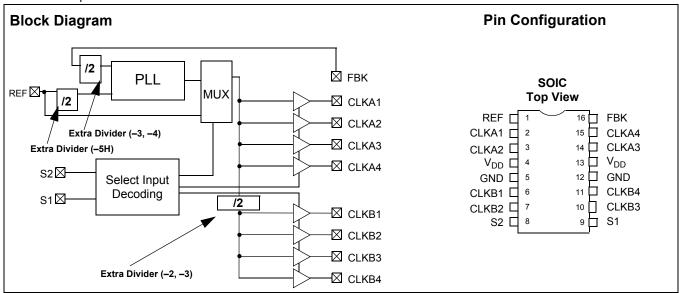
Multiple CY2308 devices can accept the same input clock and distribute it in a system. In this case, the skew between the outputs of two devices is guaranteed to be less than 700 ps.

The CY2308 is available in five different configurations, as shown in the "Available CY2308 Configurations" table on page 2. The CY2308-1 is the base part, where the output frequencies equal the reference if there is no counter in the feedback path. The CY2308-1H is the high-drive version of the -1, and rise and fall times on this device are much faster.

The CY2308–2 allows the user to obtain 2X and 1X frequencies on each output bank. The exact configuration and output frequencies depends on which output drives the feedback pin. The CY2308–3 allows the user to obtain 4X and 2X frequencies on the outputs.

The CY2308–4 enables the user to obtain 2X clocks on all outputs. Thus, the part is extremely versatile, and can be used in a variety of applications.

The CY2308–5H is a high-drive version with REF/2 on both banks.





Pin Description

| Pin | Signal | Description |
|-----|----------------------|--|
| 1 | REF ^[1] | Input reference frequency, 5V tolerant input |
| 2 | CLKA1 ^[2] | Clock output, Bank A |
| 3 | CLKA2 ^[2] | Clock output, Bank A |
| 4 | V _{DD} | 3.3V supply |
| 5 | GND | Ground |
| 6 | CLKB1 ^[2] | Clock output, Bank B |
| 7 | CLKB2 ^[2] | Clock output, Bank B |
| 8 | S2 ^[3] | Select input, bit 2 |
| 9 | S1 ^[3] | Select input, bit 1 |
| 10 | CLKB3 ^[2] | Clock output, Bank B |
| 11 | CLKB4 ^[2] | Clock output, Bank B |
| 12 | GND | Ground |
| 13 | V _{DD} | 3.3V supply |
| 14 | CLKA3 ^[2] | Clock output, Bank A |
| 15 | CLKA4 ^[2] | Clock output, Bank A |
| 16 | FBK | PLL feedback input |

Select Input Decoding

| S2 | S1 | CLOCK A1-A4 | CLOCK B1-B4 | Output Source | PLL Shutdown |
|----|----|-----------------------|-----------------------|---------------|--------------|
| 0 | 0 | Three-State | Three-State | PLL | Y |
| 0 | 1 | Driven | Three-State | PLL | N |
| 1 | 0 | Driven ^[4] | Driven ^[4] | Reference | Y |
| 1 | 1 | Driven | Driven | PLL | N |

Available CY2308 Configurations

| Device | Feedback From | Bank A Frequency | Bank B Frequency |
|-----------|------------------|------------------|---------------------------------------|
| CY2308-1 | Bank A or Bank B | Reference | Reference |
| CY2308-1H | Bank A or Bank B | Reference | Reference |
| CY2308-2 | Bank A | Reference | Reference/2 |
| CY2308-2 | Bank B | 2 X Reference | Reference |
| CY2308-3 | Bank A | 2 X Reference | Reference or Reference ^[5] |
| CY2308-3 | Bank B | 4 X Reference | 2 X Reference |
| CY2308-4 | Bank A or Bank B | 2 X Reference | 2 X Reference |
| CY2308-5H | Bank A or Bank B | Reference /2 | Reference /2 |

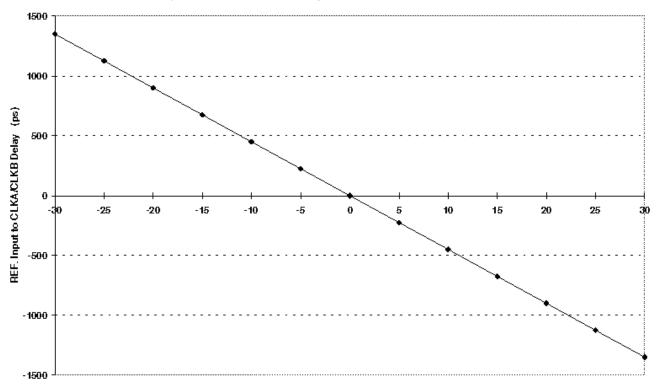
Notes:

- Weak pull-down.
 Weak pull-down on all outputs.
 Weak pull-ups on these inputs.
 Outputs inverted on 2308–2 and 2308–3 in bypass mode, S2 = 1 and S1 = 0.
 Output phase is indeterminant (0° or 180° from input clock). If phase integrity is required, use the CY2308–2.



Zero Delay and Skew Control

REF. Input to CLKA/CLKB Delay v/s Difference in Loading between FBK pin and CLKA/CLKB Pins



Output Load Difference: FBK Load - CLKA/CLKB Load (pF)

To close the feedback loop of the CY2308, the FBK pin can be driven from any of the eight available output pins. The output driving the FBK pin will be driving a total load of 7 pF plus any additional load that it drives. The relative loading of this output (with respect to the remaining outputs) can adjust the input-output delay. This is shown in the graph above.

For applications requiring zero input-output delay, all outputs including the one providing feedback should be equally loaded. If input-output delay adjustments are required, use the above graph to calculate loading differences between the feedback output and remaining outputs.

For zero output-output skew, be sure to load outputs equally. For further information on using CY2308, refer to the application note "CY2308: Zero Delay Buffer."

Maximum Ratings

| Supply Voltage to Ground Potentia | I0.5V to +7.0V |
|--|--------------------------------|
| DC Input Voltage (Except Ref) | 0.5V to V _{DD} + 0.5V |
| DC Input Voltage REF | –0.5 to 7V |
| Storage Temperature | –65°C to +150°C |
| Junction Temperature | 150°C |
| Static Discharge Voltage (per MIL-STD-883, Method 3015). | >2000V |

Operating Conditions for CY2308SC-XX Commercial Temperature Devices

| Parameter | Description | Min. | Max. | Unit |
|--------------------------------|--|------|------|------|
| V _{DD} Supply Voltage | | 3.0 | 3.6 | V |
| T _A | Operating Temperature (Ambient Temperature) | 0 | 70 | °C |
| C _L | Load Capacitance, below 100 MHz | | 30 | pF |
| | Load Capacitance, from 100 MHz to 133 MHz | | 15 | pF |
| C _{IN} | Input Capacitance ^[6] | | 7 | pF |
| t _{PU} | Power-up time for all V _{DD} s to reach minimum specified voltage (power ramps must be monotonic) | 0.05 | 50 | ms |

Note:

^{6.} Applies to both Ref Clock and FBK.



Electrical Characteristics for CY2308SC-XX Commercial Temperature Devices

| Parameter | Description | Test Conditions | Min. | Max. | Unit |
|---------------------------|------------------------------------|---|------|-------------------|------|
| V _{IL} | Input LOW Voltage | | | 0.8 | V |
| V _{IH} | Input HIGH Voltage | | 2.0 | | V |
| I _{IL} | Input LOW Current | V _{IN} = 0V | | 50.0 | μΑ |
| I _{IH} | Input HIGH Current | $V_{IN} = V_{DD}$ | | 100.0 | μΑ |
| V _{OL} | Output LOW Voltage ^[7] | I _{OL} = 8 mA (-1, -2, -3, -4) I _{OL} = 12 mA (-1H, -5H) | | 0.4 | V |
| V _{OH} | Output HIGH Voltage ^[7] | I _{OH} = -8 mA (-1, -2, -3, -4) I _{OH} = -12 mA (-1H, -5H) | 2.4 | | V |
| I _{DD} (PD mode) | Power Down Supply Current | REF = 0 MHz | | 12.0 | μΑ |
| I _{DD} | Supply Current | Unloaded outputs, 100-MHz REF, | | 45.0 | mA |
| | | Select inputs at V _{DD} or GND | | 70.0 (–1H,–5H) | mA |
| | | Unloaded outputs, 66-MHz REF (-1, -2, -3, -4) | | 32.0 | mA |
| | | Unloaded outputs, 33-MHz REF (-1, -2, -3, -4) | | 18.0 | mA |

Note:
7. Parameter is guaranteed by design and characterization. Not 100% tested in production.



Switching Characteristics for CY2308SC-XX Commercial Temperature Devices [8]

| Parameter | Name | Test Conditions | Min. | Тур. | Max. | Unit |
|-------------------|--|--|------|------|-------|------|
| t ₁ | Output Frequency | 30-pF load, All devices | 10 | | 100 | MHz |
| t ₁ | Output Frequency | 20-pF load, -1H, -5H devices ^[9] | 10 | | 133.3 | MHz |
| t ₁ | Output Frequency | 15-pF load, -1, -2, -3, -4 devices | 10 | | 133.3 | MHz |
| | Duty Cycle ^[7] = $t_2 \div t_1$ (-1, -2, -3, -4, -1H, -5H) | Measured at 1.4V, F _{OUT} = 66.66 MHz 30-pF load | 40.0 | 50.0 | 60.0 | % |
| | Duty Cycle ^[7] = $t_2 \div t_1$ (-1, -2, -3, -4, -1H, -5H) | Measured at 1.4V, F _{OUT} <50.0 MHz 15-pF load | 45.0 | 50.0 | 55.0 | % |
| t ₃ | Rise Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 30-pF load | | | 2.20 | ns |
| t ₃ | Rise Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 15-pF load | | | 1.50 | ns |
| t ₃ | Rise Time ^[7] (–1H, –5H) | Measured between 0.8V and 2.0V, 30-pF load | | | 1.50 | ns |
| t ₄ | Fall Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 30-pF load | | | 2.20 | ns |
| t ₄ | Fall Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 15-pF load | | | 1.50 | ns |
| t ₄ | Fall Time ^[7] (–1H, –5H) | Measured between 0.8V and 2.0V, 30-pF load | | | 1.25 | ns |
| t ₅ | Output to Output Skew on same Bank (-1, -2, -3, -4) ^[7] | All outputs equally loaded | | | 200 | ps |
| | Output to Output Skew (–1H, –5H) | All outputs equally loaded | | | 200 | ps |
| | Output Bank A to Output Bank B Skew (-1, -4, -5H) | All outputs equally loaded | | | 200 | ps |
| | Output Bank A to Output Bank B Skew (-2, -3) | All outputs equally loaded | | | 400 | ps |
| t ₆ | Delay, REF Rising Edge to FBK Rising Edge ^[7] | Measured at V _{DD} /2 | | 0 | ±250 | ps |
| t ₇ | Device to Device Skew ^[7] | Measured at V _{DD} /2 on the FBK pins of devices | | 0 | 700 | ps |
| t ₈ | Output Slew Rate ^[7] | Measured between 0.8V and 2.0V on –1H, –5H device using Test Circuit #2 | 1 | | | V/ns |
| t _J | Cycle to Cycle Jitter ^[7] (–1, –1H, –4, –5H) | Measured at 66.67 MHz, loaded outputs, 15-pF load | | | 200 | ps |
| | | Measured at 66.67 MHz, loaded outputs, 30-pF load | | | 200 | ps |
| | | Measured at 133.3 MHz, loaded outputs, 15-pF load | | | 100 | ps |
| t _J | Cycle to Cycle Jitter ^[7] (–2, –3) | Measured at 66.67 MHz, loaded outputs 30-pF load | | | 400 | ps |
| | | Measured at 66.67 MHz, loaded outputs 15-pF load | | | 400 | ps |
| t _{LOCK} | PLL Lock Time ^[7] | Stable power supply, valid clocks presented on REF and FBK pins | | | 1.0 | ms |

Notes:

8. All parameters are specified with loaded outputs.
9. CY2308–5H has maximum input frequency of 133.33 MHz and maximum output of 66.67 MHz.



Operating Conditions for CY2308SI-XX Industrial Temperature Devices

| Parameter | Description | Min. | Max. | Unit |
|-----------------|--|------|------|------|
| V_{DD} | Supply Voltage | 3.0 | 3.6 | V |
| T _A | Operating Temperature (Ambient Temperature) | -40 | 85 | °C |
| C _L | Load Capacitance, below 100 MHz | | 30 | pF |
| | Load Capacitance, from 100 MHz to 133 MHz | | 15 | pF |
| C _{IN} | Input Capacitance ^[6] | | 7 | pF |
| t _{PU} | Power-up time for all V _{DD} s to reach minimum specified voltage (power ramps must be monotonic) | 0.05 | 50 | ms |

Electrical Characteristics for CY2308SI-XX Industrial Temperature Devices

| Parameter | Description | Test Conditions | Min. | Max. | Unit |
|---------------------------|------------------------------------|---|------|-------------|------|
| V _{IL} | Input LOW Voltage | | | 0.8 | V |
| V _{IH} | Input HIGH Voltage | | 2.0 | | V |
| I _{IL} | Input LOW Current | V _{IN} = 0V | | 50.0 | μА |
| I _{IH} | Input HIGH Current | $V_{IN} = V_{DD}$ | | 100.0 | μА |
| V _{OL} | Output LOW Voltage ^[7] | I _{OL} = 8 mA (-1, -2, -3, -4) I _{OL} = 12 mA (-1H, -5H) | | 0.4 | V |
| V _{OH} | Output HIGH Voltage ^[7] | I _{OH} = -8 mA (-1, -2, -3, -4) I _{OH} = -12 mA (-1H, -5H) | 2.4 | | V |
| I _{DD} (PD mode) | Power Down Supply Current | REF = 0 MHz | | 25.0 | μА |
| I _{DD} | Supply Current | Unloaded outputs, 100 MHz, | | 45.0 | mA |
| | | Select inputs at V _{DD} or GND | | 70(–1H,–5H) | mA |
| | | Unloaded outputs, 66-MHz REF (-1, -2, -3, -4) | | 35.0 | mA |
| | | Unloaded outputs, 66-MHz REF (-1, -2, -3, -4) | | 20.0 | mA |



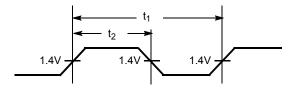
Switching Characteristics for CY2308SI-XX Industrial Temperature Devices [8]

| Parameter | Name | Test Conditions | Min. | Тур. | Max. | Unit |
|-------------------|--|---|------|------|-------|------|
| t ₁ | Output Frequency | 30-pF load, All devices | 10 | | 100 | MHz |
| t ₁ | Output Frequency | 20-pF load, –1H, –5H devices ^[9] | 10 | | 133.3 | MHz |
| t ₁ | Output Frequency | 15-pF load, -1, -2, -3, -4 devices | 10 | | 133.3 | MHz |
| | Duty Cycle ^[7] = $t_2 \div t_1$ (-1, -2, -3, -4, -1H, -5H) | Measured at 1.4V, F _{OUT} = 66.66 MHz 30-pF load | 40.0 | 50.0 | 60.0 | % |
| | Duty Cycle ^[7] = $t_2 \div t_1$ (-1, -2, -3, -4, -1H, -5H) | Measured at 1.4V, F _{OUT} <50.0 MHz 15-pF load | 45.0 | 50.0 | 55.0 | % |
| t ₃ | Rise Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 30-pF load | | | 2.50 | ns |
| t ₃ | Rise Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 15-pF load | | | 1.50 | ns |
| t ₃ | Rise Time ^[7] (–1H, –5H) | Measured between 0.8V and 2.0V, 30-pF load | | | 1.50 | ns |
| t ₄ | Fall Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 30-pF load | | | 2.50 | ns |
| t ₄ | Fall Time ^[7] (-1, -2, -3, -4) | Measured between 0.8V and 2.0V, 15-pF load | | | 1.50 | ns |
| t ₄ | Fall Time ^[7] (–1H, –5H) | Measured between 0.8V and 2.0V, 30-pF load | | | 1.25 | ns |
| t ₅ | Output to Output Skew on same Bank (-1, -2, -3, -4) ^[7] | All outputs equally loaded | | | 200 | ps |
| | Output to Output Skew (–1H, –5H) | All outputs equally loaded | | | 200 | ps |
| | Output Bank A to Output Bank B Skew (-1, -4, -5H) | All outputs equally loaded | | | 200 | ps |
| | Output Bank A to Output Bank B Skew (-2, -3) | All outputs equally loaded | | | 400 | ps |
| t ₆ | Delay, REF Rising Edge to FBK Rising Edge ^[7] | Measured at V _{DD} /2 | | 0 | ±250 | ps |
| t ₇ | Device to Device Skew ^[7] | Measured at $V_{DD}/2$ on the FBK pins of devices | | 0 | 700 | ps |
| t ₈ | Output Slew Rate ^[7] | Measured between 0.8V and 2.0V on –1H, –5H device using Test Circuit # 2 | 1 | | | V/ns |
| t _J | Cycle to Cycle Jitter ^[7] (–1, –1H, –4, –5H) | Measured at 66.67 MHz, loaded outputs, 15-pF load | | | 200 | ps |
| | | Measured at 66.67 MHz, loaded outputs, 30-pF load | | | 200 | ps |
| | | Measured at 133.3 MHz, loaded outputs, 15 pF load | | | 100 | ps |
| t _J | Cycle to Cycle Jitter ^[7] (–2, –3) | Measured at 66.67 MHz, loaded outputs 30-pF load | | | 400 | ps |
| | | Measured at 66.67 MHz, loaded outputs 15-pF load | | | 400 | ps |
| t _{LOCK} | PLL Lock Time ^[7] | Stable power supply, valid clocks presented on REF and FBK pins | | | 1.0 | ms |

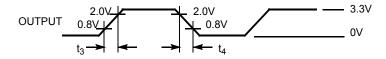


Switching Waveforms

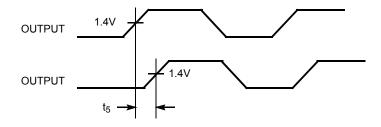
Duty Cycle Timing



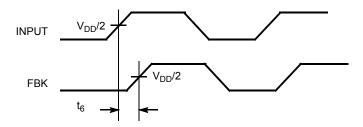
All Outputs Rise/Fall Time



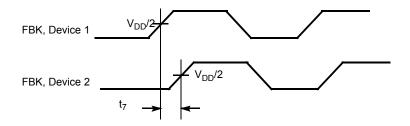
Output-Output Skew



Input-Output Propagation Delay

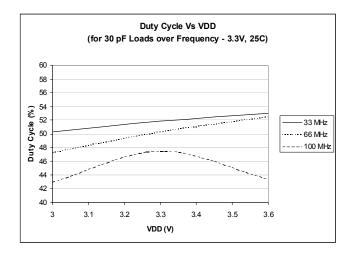


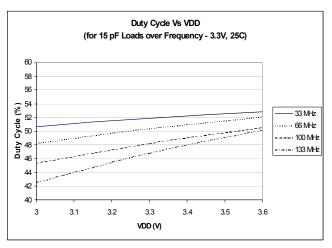
Device-Device Skew

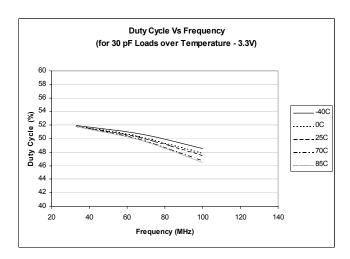


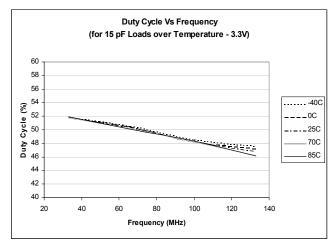


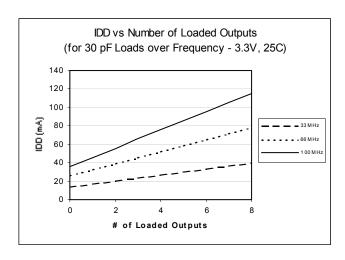
Typical Duty Cycle $^{[10]}$ and $I_{\mbox{\scriptsize DD}}$ Trends $^{[11]}$ for CY2308–1,2,3,4

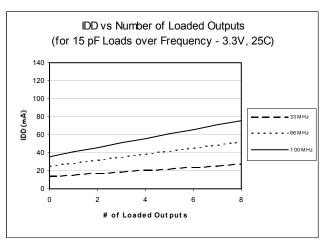












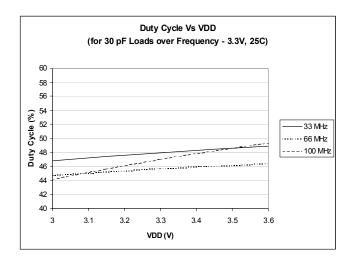
Notes:

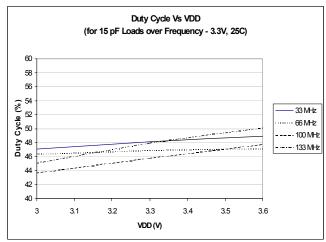
10. Duty Cycle is taken from typical chip measured at 1.4V.

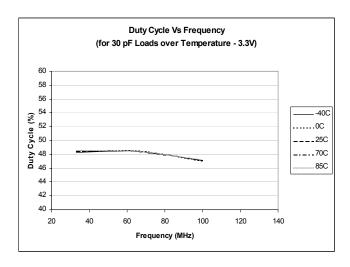
^{11.} I_{DD} data is calculated from I_{DD} = I_{CORE} + nCVf, where I_{CORE} is the unloaded current. (n = # of outputs; C = Capacitance load per output (F); V = Voltage Supply (V); f = frequency (Hz))

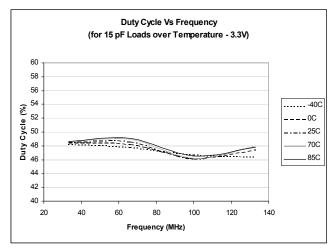


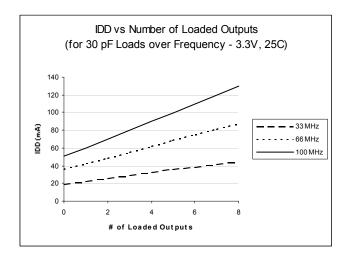
Typical Duty $\rm Cycle^{[10]}$ and $\rm I_{DD}$ $\rm Trends^{[11]}$ for CY2308–1H, 5H

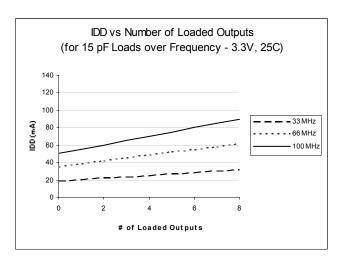








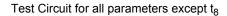


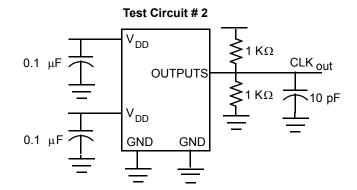




Test Circuits

Test Circuit # 1 0.1 μ F V_{DD} OUTPUTS C_{LOAD} C_{LOAD} O.1 μ F C_{LOAD} C_{LOAD} C_{LOAD}





Test Circuit for t_8 , Output slew rate on -1H, -5 device



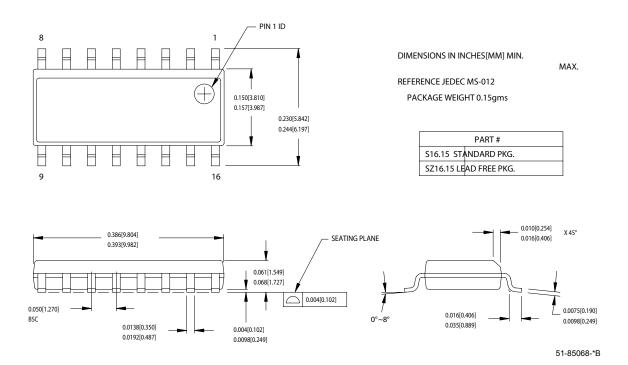
Ordering Information

| Ordering Code | Package Name | Package Type | Operating Range |
|---------------|--------------|----------------------|-----------------|
| CY2308SC-1 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-1 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SC-1H | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-1H | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308ZC-1H | Z16 | 16-pin 150-mil TSSOP | Commercial |
| CY2308ZI-1H | Z16 | 16-pin 150-mil TSSOP | Industrial |
| CY2308SC-2 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-2 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SC-3 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-3 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SC-4 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-4 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SC-5H | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SI-5H | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308ZC-5H | Z16 | 16-pin 150-mil TSSOP | Commercial |
| CY2308ZI-5H | Z16 | 16-pin 150-mil TSSOP | Industrial |
| Lead Free | | | |
| CY2308SXC-1 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-1 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SXC-1H | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-1H | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308ZXC-1H | Z16 | 16-pin 150-mil TSSOP | Commercial |
| CY2308ZXI-1H | Z16 | 16-pin 150-mil TSSOP | Industrial |
| CY2308SXC-2 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-2 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SXC-3 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-3 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SXC-4 | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-4 | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308SXC-5H | S16 | 16-pin 150-mil SOIC | Commercial |
| CY2308SXI-5H | S16 | 16-pin 150-mil SOIC | Industrial |
| CY2308ZXC-5H | Z16 | 16-pin 150-mil TSSOP | Commercial |
| CY2308ZXI-5H | Z16 | 16-pin 150-mil TSSOP | Industrial |
| | | | |

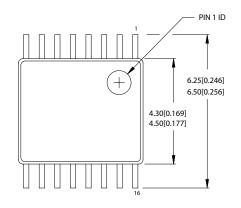


Package Drawings and Dimensions

16-Lead (150-Mil) SOIC S16.15



16-lead TSSOP 4.40 MM Body Z16.173

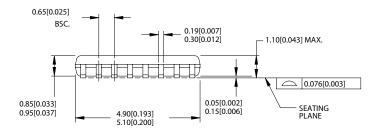


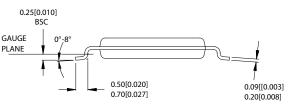
DIMENSIONS IN MM[INCHES] MIN. MAX.

REFERENCE JEDEC MO-153

PACKAGE WEIGHT 0.05 gms

| PART # | | |
|----------|----------------|--|
| Z16.173 | STANDARD PKG. | |
| ZZ16.173 | LEAD FREE PKG. | |





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.Document History Page

| Document Title: CY2308 3.3V Zero Delay Buffer Document Number: 38-07146 | | | | |
|---|---------|---------------|--------------------|---|
| REV. | ECN NO. | Issue Date | Orig. of Change | Description of Change |
| ** | 110255 | 12/17/01 | SZV | Change from Spec number: 38-00528 to 38-07146 |
| *A | 118722 | 10/31/02 | RGL | Added Note 1 in page 2. |
| *B | 121832 | 12/14/02 | RBI | Power up requirements added to Operating Conditions Information |
| *C | 235854 | See ECN | RGL | Added Lead Free Devices |